

MAXIM

Low-Power, Monolithic, CMOS Analog Multiplexers

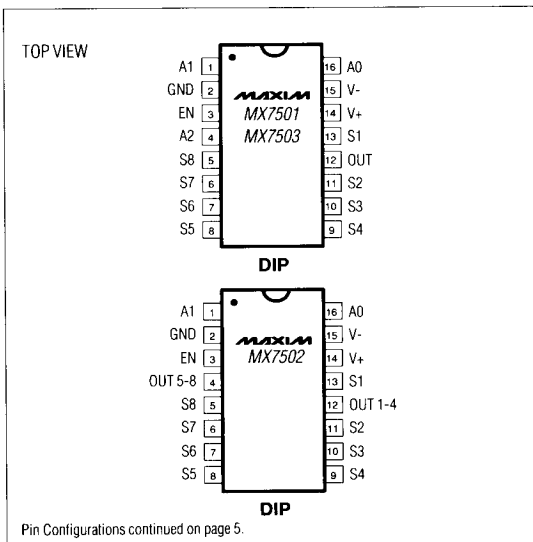
General Description

Maxim's MX7501/7502/7503 are low-power, monolithic, CMOS analog multiplexers. The MX7501 is a single-ended, 8-channel (1-of-8) multiplexer, while the MX7502 is a differential, 4-channel (2-of-8) multiplexer. The MX7503 is identical to the MX7501, except the enable logic is inverted (channels are on with Enable low). These devices are plug-in upgrades for the industry-standard "7501/7502/7503": the MX7501/7502/7503 consume significantly less power (6mW Max) and offer a wider operating range of power-supply voltages (a single supply of +10V to +30V, or dual supplies of $\pm 5V$ to $\pm 18V$). The MX7501/7502/7503 also feature Maxim's standard latchup-proof CMOS construction, and they are both TTL and CMOS compatible.

Applications

Control Systems
Data Logging Systems
Aircraft Heads-Up Displays
Data Acquisition Systems
Signal Routing
Portable Equipment

Pin Configurations



Features

- ◆ Drop-In Upgrade for Industry-Standard "7501/7502/7503"
- ◆ Low-Power Consumption: 6mW Max
- ◆ Operable with $\pm 4.5V$ to $\pm 18V$ Supplies
- ◆ Latchup-Proof Construction
- ◆ Symmetrical, Bidirectional Operation
- ◆ TTL and CMOS Compatible Logic Inputs
- ◆ Monolithic, Low-Power CMOS Design

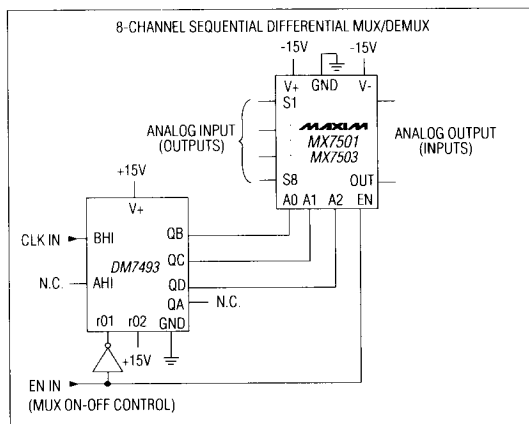
Ordering Information

PART	TEMP. RANGE	PIN-PACKAGE
MX7501JN	0°C to +70°C	16 Plastic DIP
MX7501KN	0°C to +70°C	16 Plastic DIP
MX7501C/D*	0°C to +70°C	Dice
MX7501JQ	-40°C to +85°C	16 CERDIP
MX7501KQ	-40°C to +85°C	16 CERDIP
MX7501SQ	-55°C to +125°C	16 CERDIP
MX7501SE*	-55°C to +125°C	20 LCC

* For Dice, Plastic Leadless Chip Carrier (PLCC), Ceramic Leadless Chip Carrier (LCC) and Ceramic Sidebrase (Ceramic SB), contact factory for availability.

Ordering information continued on page 6.

Typical Operating Circuit


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ABSOLUTE MAXIMUM RATINGS

V+ to GND	+18V
V- to GND	-18V
V Between Any Switch Terminals (Note 1)	25V
Digital Input Voltage Range	V+ to GND
Max Overvoltage at VOUT (Vs)	V-, V+
Switch Current (Is, Continuous 1 Channel)	20mA
Switch Current (Is, Surge 1 Channel, 1ms Duration, 10% Duty Cycle)	35mA

Power Dissipation (Any Package)	
Up to +50°C	1000mW
Derate above +50°C by	10mW/°C
Operating Temperature	
MX750_JN/KN/C/D	0°C to +70°C
MX750_JQ/KQ	-40°C to +85°C
MX750_SQ/SE	-55°C to +125°C
Storage Temperature	-65°C to +150°C

Note 1: Do not apply voltages higher than V+ and V- to any other terminal, especially when V- = V+ = 0V, all other pins should be at 0V.

Note 2: The digital control inputs are diode protected; however, permanent damage may occur on unconnected units under high-energy electrostatic fields. Keep unused units in conductive foam at all times.

Stresses listed under "Absolute Maximum Ratings" may be applied (one at a time) to devices without resulting in permanent damage. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

ELECTRICAL CHARACTERISTICS

(V+ = +15V, V- = -15V, GND = 0V, unless otherwise noted.)

PARAMETER		SYMBOL	VERSION (Note 3)	SWITCH CONDITION	TEST CONDITIONS	+25°C			OVER SPECIFIED TEMP. RANGE			UNITS
						MIN	TYP	MAX	MIN	TYP	MAX	
ANALOG SWITCH												
Drain-Source On Resistance		r _{DS(ON)}	J, K, S	On	V _S = ±10V, I _S = 1mA	180	300			450		Ω
		r _{DS(ON)} vs. V _S	All	On	V _S = ±10V, I _S = 1mA	15						%
Tempco of On Resistance		r _{DS(ON)} vs. Temp.	All	On	V _S = 0V, I _S = 1mA					0.5		%/°C
Difference in On Resistance Between Channels		Δr _{DS(ON)} Between Switches	All	On	V _S = 0V, I _S = 1mA	4						%
		Δr _{DS(ON)} vs. Temp. Between Switches	All	On	V _S = 0V, I _S = 1mA					0.05		%/°C
Source-Off Leakage Current		I _{S(OFF)}	J, K	Off	V _S = -10V, V _D = +10V and V _S = +10V, V _D = -10V "Enable Low"	±0.2	2			±50		nA
			S	Off			±0.5			±50		
Drain-Off Leakage Current	MX7501	I _{D(OFF)}	J, K	Off	V _S = -10V, V _D = +10V and V _S = +10V, V _D = -10V "Enable Low"		±10			±250		nA
	MX7503		S	Off			±5			±250		
	MX7502		J, K	Off			±5			±125		
			S	Off			±3			±125		
Channel-On Leakage Current I _{D(ON)} -I _S (Any Switch On)	MX7501	I _{D(ON)}	J, K	On	V _S = 0		±12			±300		nA
	MX7503		S	On	V _S = 0		±5.5			±300		
	MX7502		J, K	On	V _S = 0		±7			±175		
			S	On	V _S = 0		±3.5			±175		

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ELECTRICAL CHARACTERISTICS (continued)

(V+ = +15V, V- = -15V, GND = 0V, unless otherwise noted.)

PARAMETER	SYMBOL	VERSION (Note 3)	SWITCH CONDITION	TEST CONDITIONS	+25°C			OVER SPECIFIED TEMP. RANGE			UNITS
					MIN	TYP	MAX	MIN	TYP	MAX	
DIGITAL CONTROL											
Address-Input Threshold (Low)	V _{INL}	All						0.8			V
Address-Input Threshold (High)	V _{INH}	J		(Note 4)				3.0			V
		K, S		(Note 4)				2.4			
Input Logic Current	I _{INL} or I _{INH}	All			0.1	10		0.1	30		μA
Address-Input Capacitance	C _{IN}	All			3			3			pF
DYNAMIC CHARACTERISTICS (Note 5)											
Switching Time of Multiplexers (Figure 1)	t _{TRANSITION}	All	Off	V _{IN} = 0V to 5V	700	1000		1500			ns
Break-Before-Make Interval (Figure 2)	t _{OPEN}	All	Off	V _{IN} = 0V to 5V	100			100			ns
Enable Turn-On Time (Figure 3)	t _{ON} (EN)	All	On	V _{EN} = 0V to 5V	0.8	1.5		2.0			μs
Enable Turn-Off Time (Figure 3)	t _{OFF} (EN)	All	Off	V _{EN} = 0V to 5V	0.8	1		1.5			μs
Off Isolation	OIRR	All	Off	V _{EN} = 0, R _L = 200Ω, C _L = 3pF, V _S = 3V _{RMS} , f = 50kHz	70			70			dB
Source-Off Capacitance	C _{S(OFF)}	All	Off		5						pF
Drain-Off Capacitance	C _{D(OFF)}	MX7501 MX7503	Off		40						pF
		MX7502	Off		20						
Source-to-Drain Capacitance	C _{S-D}	All	Off		0.5						pF

Note 3: JN/KN versions specified for 0°C to +70°C; JQ/KQ versions for -40°C to +85°C; SQ/SE versions for -55°C to +125°C.

Note 4: A pull-up resistor, typically 1-2kΩ is required to make the J version compatible with TTL/DTL. The maximum value is determined by the output leakage current of the driver gate when in the high state.

Note 5: AC parameters are sample tested to ensure conformance to specifications.

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ELECTRICAL CHARACTERISTICS (continued)

($V_+ = +15V$, $V_- = -15V$, $GND = 0V$, unless otherwise noted.)

PARAMETER	SYMBOL	VERSION (Note 3)	SWITCH CONDITION	TEST CONDITIONS	+25° C			OVER SPECIFIED TEMP. RANGE			UNITS
					MIN	TYP	MAX	MIN	TYP	MAX	
POWER SUPPLY											
Positive Supply Current	I+	All	Off	Digital Inputs = 0V	0.05	0.1		0.2			mA
Negative Supply Current	I-	All	Off	Digital Inputs = 0V	0.05	0.1		0.2			mA
Positive Supply Current	I+	All	On	Digital Inputs = 5V	0.15	0.3		0.5			mA
Negative Supply Current	I-	All	On	Digital Inputs = 5V	0.05	0.1		0.2			mA
Power-Supply Range for Continuous Operation	VOP	All		(Note 6)	±4.5		±18				V

Note 3: JN/KN versions specified for 0°C to +70°C; JQ/KQ versions for -40°C to +85°C; SQ/SE versions for -55°C to +125°C.

Note 4: A pull-up resistor, typically 1-2k Ω is required to make the J version compatible with TTL/DTL. The maximum value is determined by the output leakage current of the driver gate when in the high state.

Note 5: AC parameters are sample tested to ensure conformance to specifications.

Note 6: Guaranteed, but not tested. Electrical Characteristics will change when power supplies other than $\pm 15V$ are used.

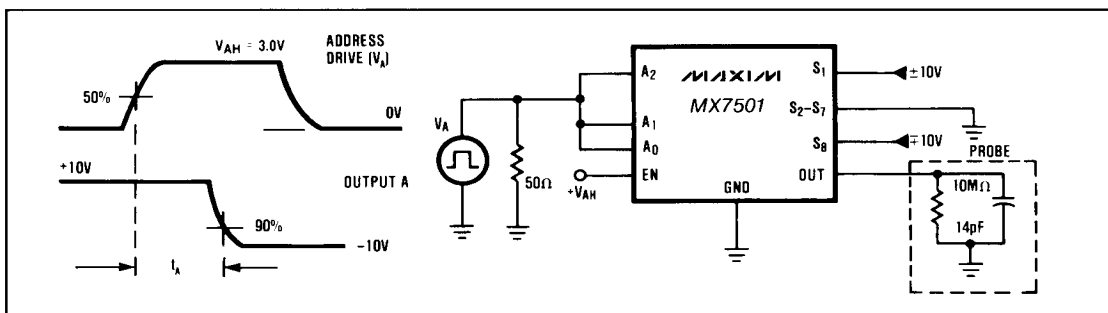


Figure 1. Transition Time vs. Logic Level (High)

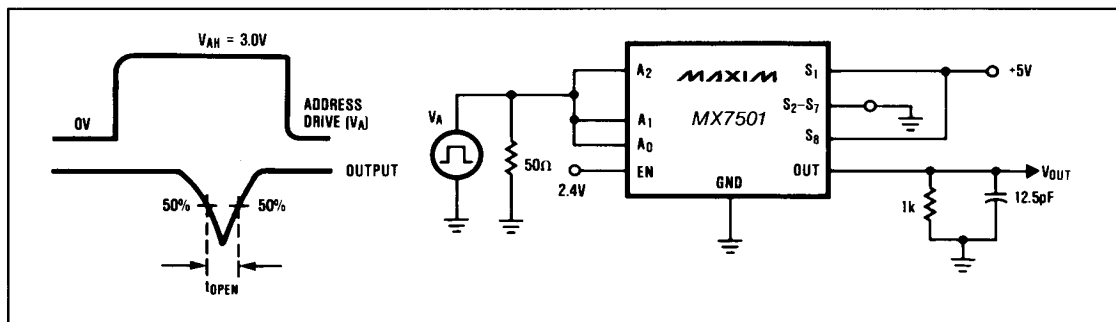


Figure 2. Break-Before-Make Interval (t_{OPEN})

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MX7501/7502/7503

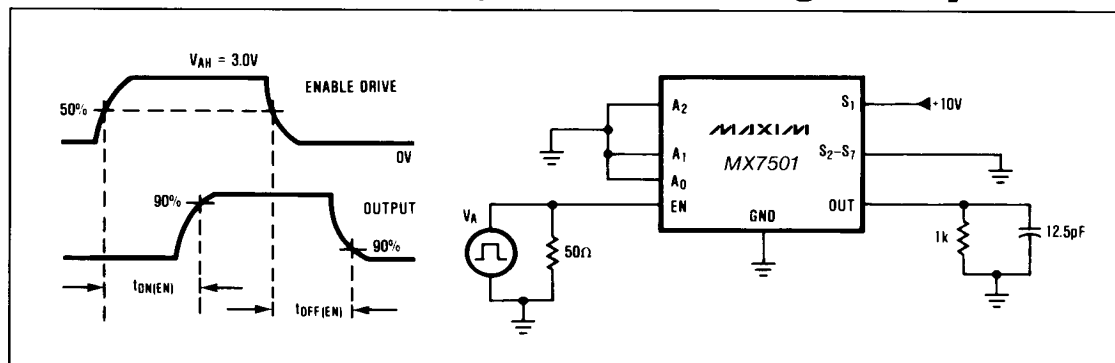


Figure 3. Enable Turn-On/Turn-Off Time

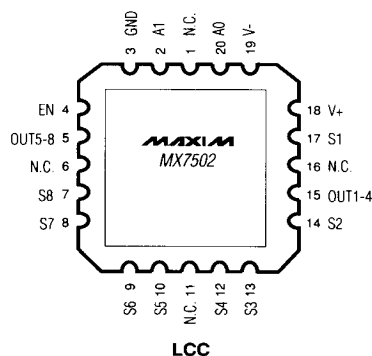
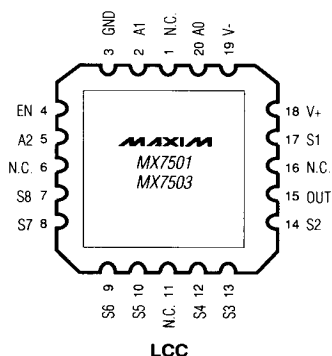
TRUTH TABLES

MX7501				
A2	A1	A0	EN	"ON"
0	0	0	1	1
0	0	1	1	2
0	1	0	1	3
0	1	1	1	4
1	0	0	1	5
1	0	1	1	6
1	1	0	1	7
1	1	1	1	8
X	X	X	0	None

MX7502			
A1	A0	EN	"ON"
0	0	1	1 & 5
0	1	1	2 & 6
1	0	1	3 & 7
1	1	1	4 & 8
X	X	0	None

MX7503				
A2	A1	A0	EN	"ON"
0	0	0	0	1
0	0	1	0	2
0	1	0	0	3
0	1	1	0	4
1	0	0	0	5
1	0	1	0	6
1	1	0	0	7
1	1	1	0	8
X	X	X	1	None

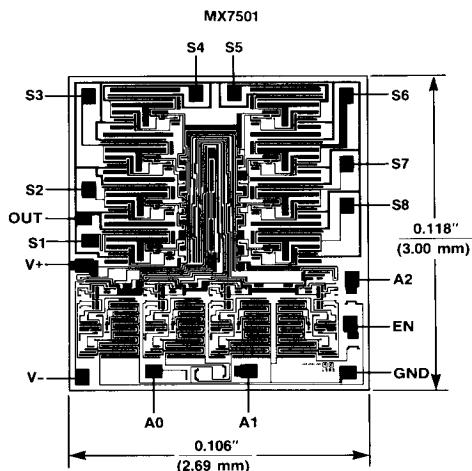
Pin Configurations (continued)



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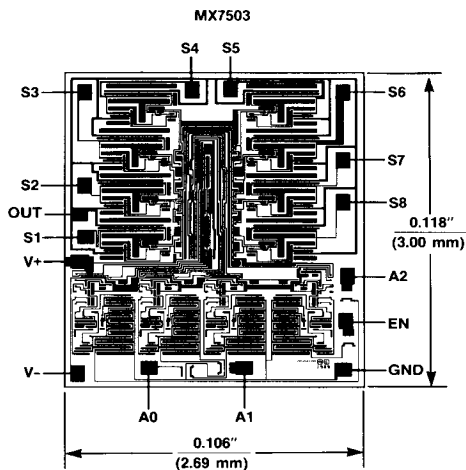
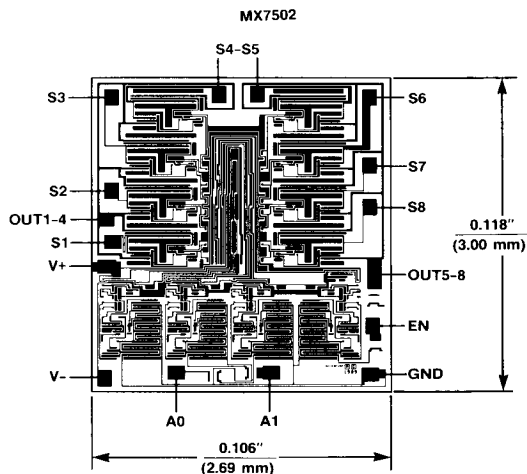
Chip Topographies

Ordering Information (continued)



PART	TEMP. RANGE	PIN-PACKAGE
MX7502JN	0°C to +70°C	16 Plastic DIP
MX7502KN	0°C to +70°C	16 Plastic DIP
MX7502C/D*	0°C to +70°C	Dice
MX7502JQ	-40°C to +85°C	16 CERDIP
MX7502KQ	-40°C to +85°C	16 CERDIP
MX7502SQ	-55°C to +125°C	16 CERDIP
MX7502SE*	-55°C to +125°C	20 LCC
MX7503JN	0°C to +70°C	16 Plastic DIP
MX7503KN	0°C to +70°C	16 Plastic DIP
MX7503C/D*	0°C to +70°C	Dice
MX7503JQ	-40°C to +85°C	16 CERDIP
MX7503KQ	-40°C to +85°C	16 CERDIP
MX7503SQ	-55°C to +125°C	16 CERDIP
MX7503SE*	-55°C to +125°C	20 LCC

* For Dice, Plastic Leadless Chip Carrier (PLCC), Ceramic Leadless Chip Carrier (LCC) and Ceramic Sidebraz (Ceramic SB), contact factory for availability.



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Printed USA

19-2863

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NOV 5 - 1990

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